

SEMICONDUCTOR DIODE CHARACTERISTICS

OMEGA TYPE ETB-68

OMEGA TYPE ETB-68 Experimental Training Board has been designed specifically for plotting Characteristics of Ge & Si Semiconductor Diodes. The board is absolutely self contained and requires no other apparatus.

Practical experience on this board carries great educative value for Science and Engineering Students.



OBJECT

- 01. To Study and Plot the Forward and Reverse Bias characteristics of (Ge & Si) Semiconductor Diodes.
- 02. To Determine the Static and Dynamic resistances of Forward Biased p-n junction of the given Diodes.

FEATURES

The board consists of following built-in parts:

- 01. 0-10V D.C. at 50mA, continuously variable with Coarse & Fine Pots, regulated Power Supply.
- 02. D.C. Voltmeter, 65mm rectangular dial, with switch selectable ranges of 1V and 10V.
- 03. D.C. Microammeter, 65mm rectangular dial, with switch selectable ranges of 50 mA and 10mA.
- 04. Ge and Si Semiconductor Diodes.
- 05. Adequate no. Of other electronic components.
- 06. Mains ON/OFF switch and Fuse.
- * The unit is operative on 230V $\pm 10\%$ at 50HzA.C. Mains.
- * Adequate no. of patch cords stackable 4mm spring loaded plug length ½ metre.
- * Good Quality, reliable terminal/sockets are provided at appropriate places on panel for connections /observation of waveforms.
- * Strongly supported by detailed Operating Instructions, giving details of Object, Theory, Design procedures, Report Suggestions and Book References.
- * Weight: 3 Kg. (Approx.)
- * Dimension: W 340 x H 110 x D 210

We are committed to the continuous development of our products, and therefore reserve the right to amend specifications without prior notice.

OMEGA ELECTRONICS